

HD74HC123A

Dual Retriggerable Monostable Multivibrators (with Clear)

REJ03D0564-0200
 (Previous ADE-205-438)
 Rev.2.00
 Oct 11, 2005

Description

This multivibrator features both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The HD74HC123A can be triggered on the positive transition of the clear while A is held low and B is held high.

The HD74HC123A is retriggerable. That is it may be triggered repeatedly while their outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature. The output pulse equation is simply: $t_w = (R_{ext}) (C_{ext})$.










Features

- High Speed Operation
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC123AP	DILP-16 pin	PRDP0016AE-B (DP-16FV)	P	—
HD74HC123AFPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

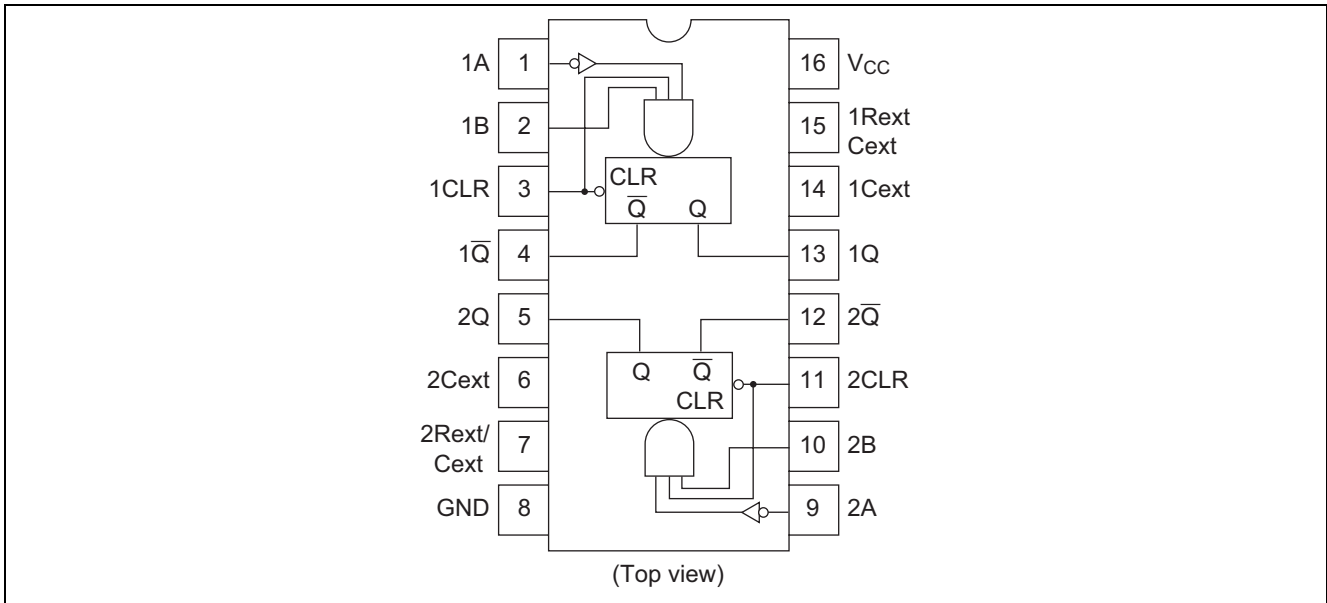
Function Table

Clear	Inputs		Outputs	
	A	B	Q	\bar{Q}
L	X	X	L	H
X	H	X	L	H
X	X	L	L	H
H	L			
H		H		
	L	H		

Note: External timing capacitance connects between C_{ext} and R_{ext}/C_{ext} .

H : High level
 L : Low level
 X : Irrelevant

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
Input / Output voltage	V _{in} , V _{out}	-0.5 to V _{CC} +0.5	V
Input / Output diode current	I _{IK} , I _{OK}	±20	mA
Output current	I _O	±25	mA
V _{CC} , GND current	I _{CC} or I _{GND}	±50	mA
Power dissipation	P _T	500	mW
Storage temperature	T _{stg}	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	2 to 6	V	
Input / Output voltage	V _{IN} , V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _a	-40 to 85	°C	
Input rise / fall time ^{*1}	t _r , t _f	0 to 1000	ns	V _{CC} = 2.0 V
		0 to 500		V _{CC} = 4.5 V
		0 to 400		V _{CC} = 6.0 V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

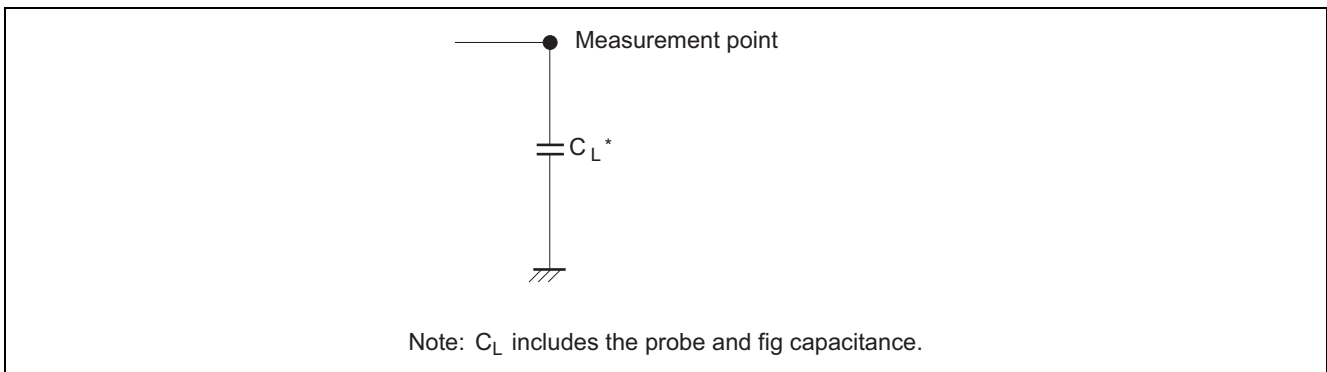
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to+85°C		Unit	Test Conditions		
			Min	Typ	Max	Min	Max				
Input voltage	V _{IH}	2.0	1.5	—	—	1.5	—	V			
		4.5	3.15	—	—	3.15	—				
		6.0	4.2	—	—	4.2	—				
	V _{IL}	2.0	—	—	0.5	—	0.5	V			
		4.5	—	—	1.35	—	1.35				
		6.0	—	—	1.8	—	1.8				
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	V _{in} = V _{IH} or V _{IL}	I _{OH} = -20 μA	
		4.5	4.4	4.5	—	4.4	—			I _{OH} = -4 mA	
		6.0	5.9	6.0	—	5.9	—			I _{OH} = -5.2 mA	
		4.5	4.18	—	—	4.13	—				
		6.0	5.68	—	—	5.63	—				
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	V _{in} = V _{IH} or V _{IL}	I _{OL} = 20 μA	
		4.5	—	0.0	0.1	—	0.1				
		6.0	—	0.0	0.1	—	0.1				
		4.5	—	—	0.26	—	0.33			I _{OL} = 4 mA	
		6.0	—	—	0.26	—	0.33			I _{OL} = 5.2 mA	
Input current	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	V _{in} = V _{CC} or GND		
Quiescent supply current	Standby state	I _{CC}	6.0	—	—	130	—	220	μA	V _{in} = V _{CC} or GND	I _{out} = 0 μA
	Active state		6.0	—	—	130	—	220			R _{ext} /C _{ext} = 0.5 V _{CC}

Switching Characteristics ($C_L = 50\text{ pF}$, Input $t_r = t_f = 6\text{ ns}$)

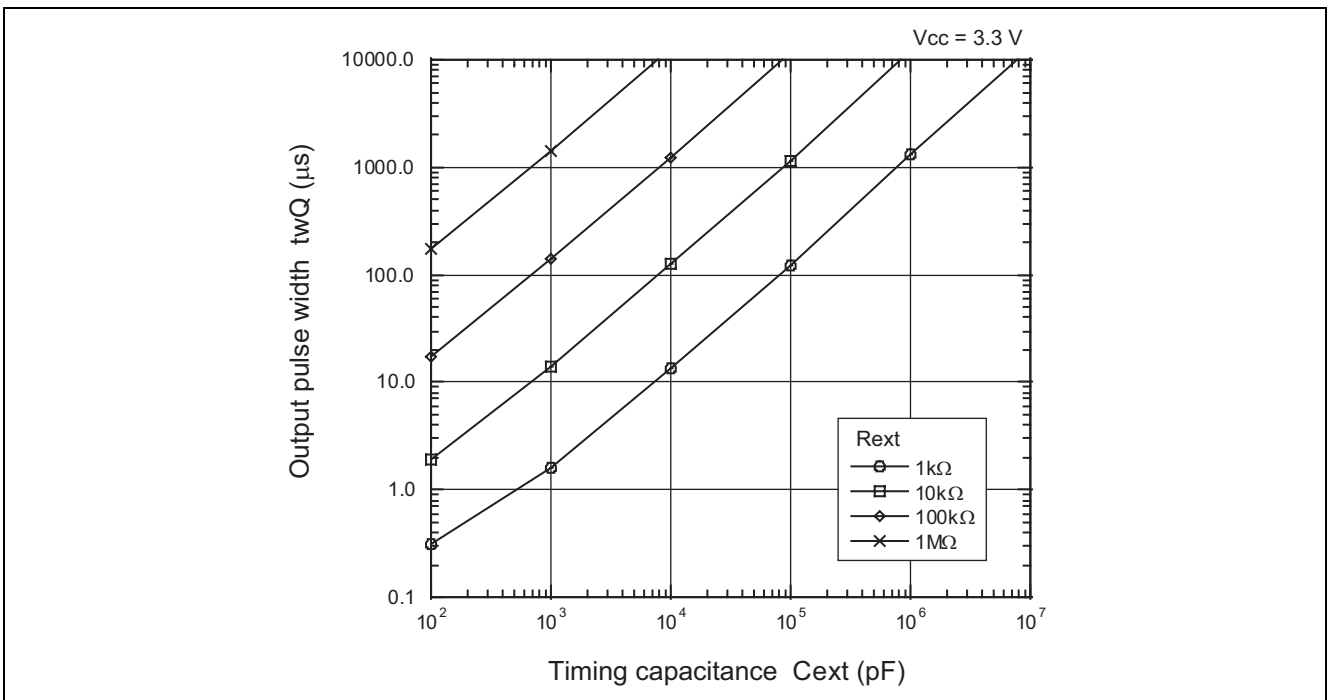
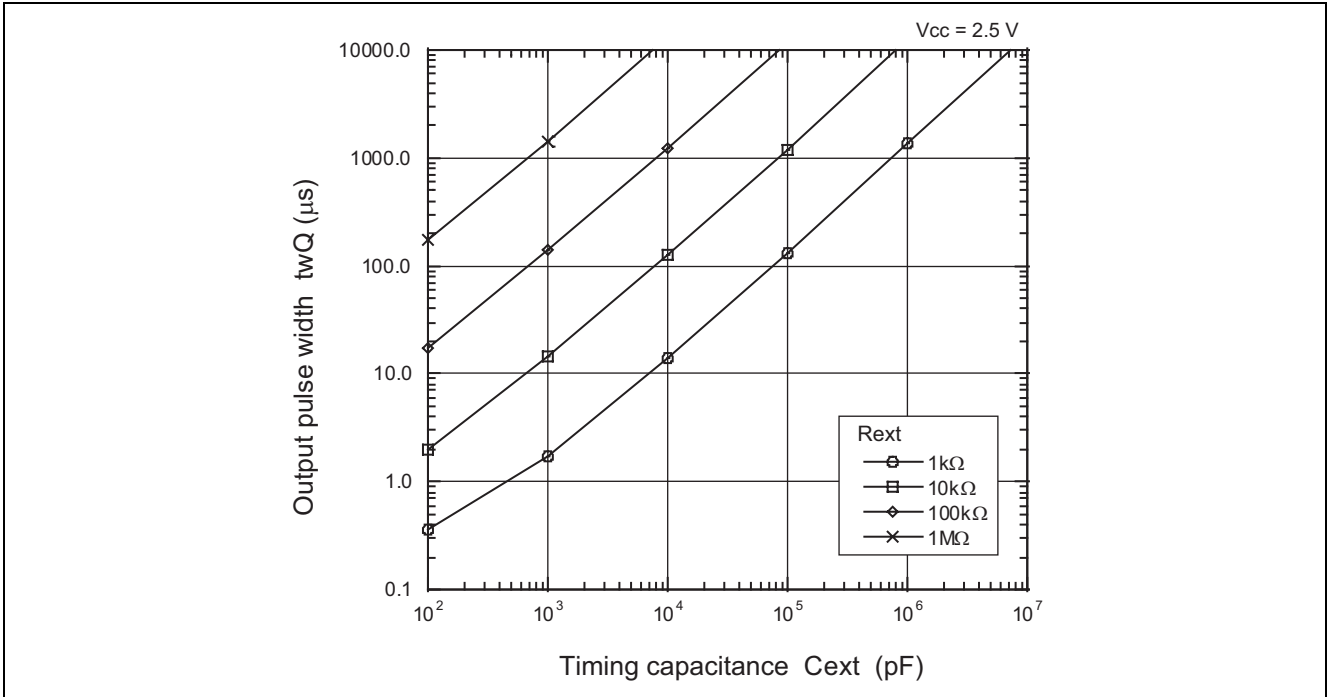
Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40\text{ to }+85^\circ\text{C}$		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Propagation delay time	t_{PLH}	2.0	—	—	210	—	265	ns	A, B or Clear to Q	
		4.5	—	22	42	—	53			
		6.0	—	—	36	—	45			
	t_{PHL}	2.0	—	—	240	—	300	ns	A, B or Clear to \bar{Q}	
		4.5	—	23	48	—	60			
		6.0	—	—	41	—	51			
	t_{PHL}	2.0	—	—	170	—	215	ns	Clear to Q	
		4.5	—	18	34	—	43			
		6.0	—	—	29	—	37			
	t_{PLH}	2.0	—	—	180	—	225	ns	Clear to \bar{Q}	
		4.5	—	16	36	—	45			
		6.0	—	—	31	—	38			
Output rise/fall time	t_{TLH}, t_{THL}	2.0	—	—	75	—	95	ns		
		4.5	—	5	15	—	19			
		6.0	—	—	13	—	16			
Pulse width	t_w	2.0	150	—	—	190	—	ns	A, B, Clear	
		4.5	30	6	—	38	—			
		6.0	26	—	—	33	—			
Minimum output pulse width	$t_{wQ(\text{min})}$	2.0	—	1.5	—	—	—	μs	Cext = 28 pF	Rest = 6 k Ω
		4.5	—	450	—	—	—			ns
		6.0	—	380	—	—	—			
Output pulse width	t_{wQ}	4.5	—	1.0	—	—	—	ms	Cext = 0.1 μF , Rest = 10 k Ω	
Input capacitance	Cin	—	—	5	10	—	10	pF		

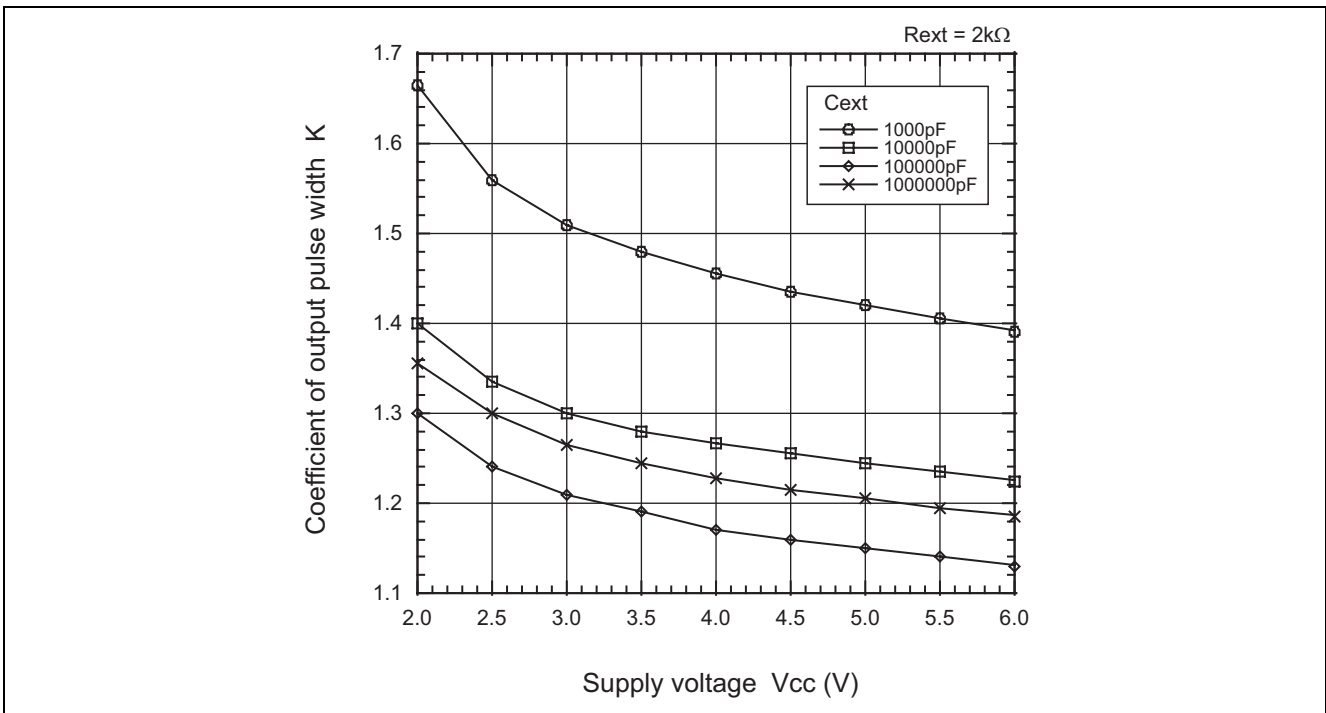
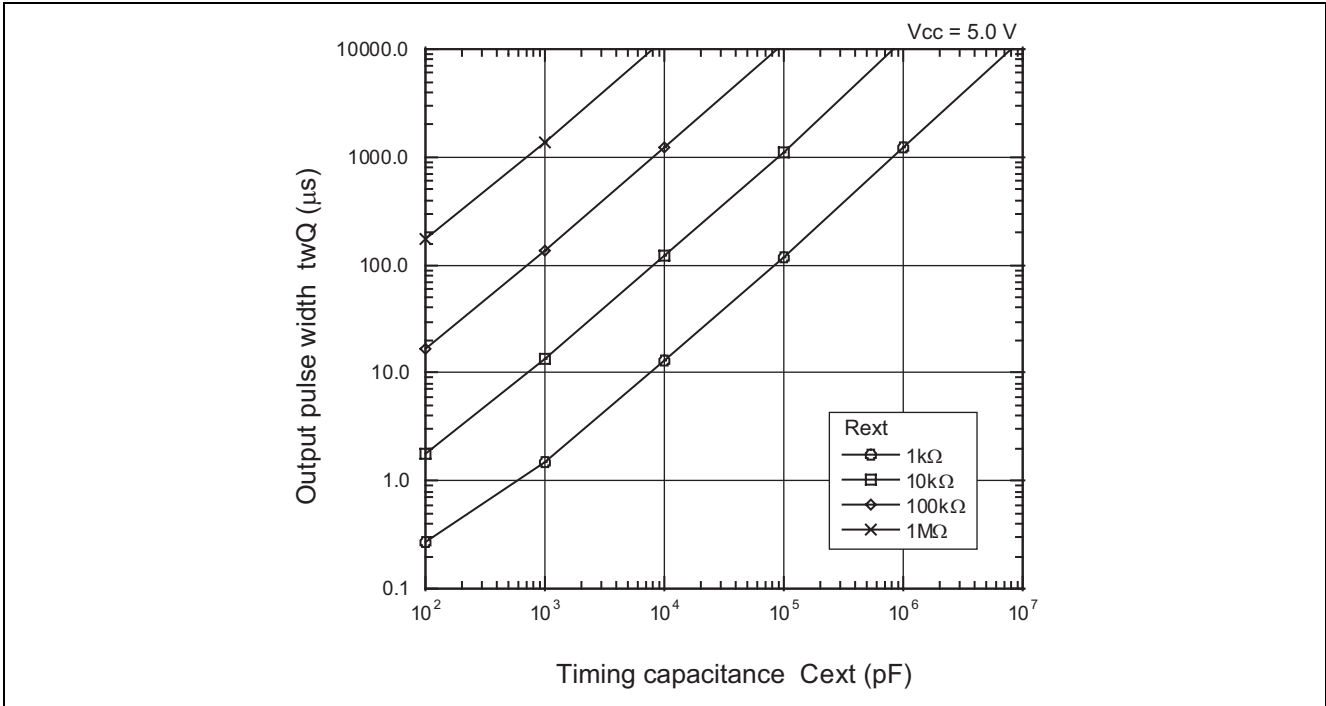
Caution in use: In order to prevent any malfunctions due to noise, connect a high-frequency performance capacitor between V_{CC} and GND, and keep the wiring between the External components and Cext, Rest/Cext pins as short as possible.

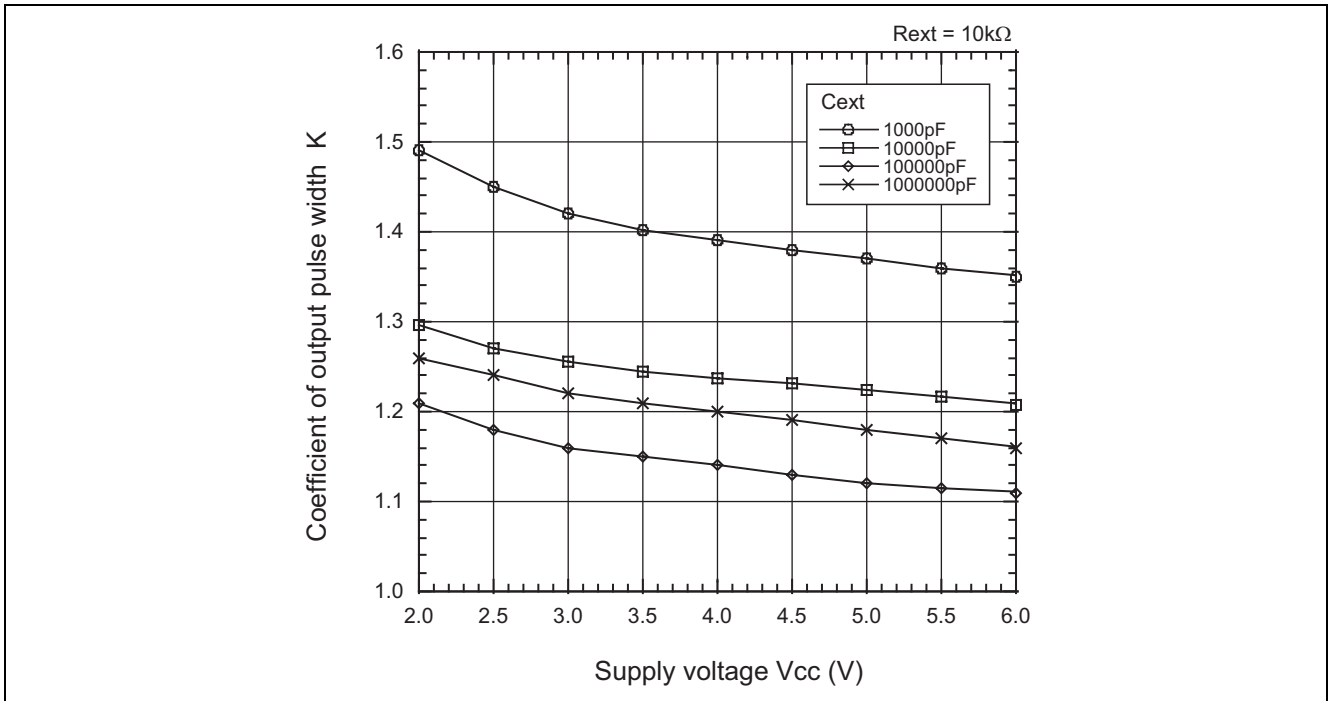
Test Circuit



Application Data

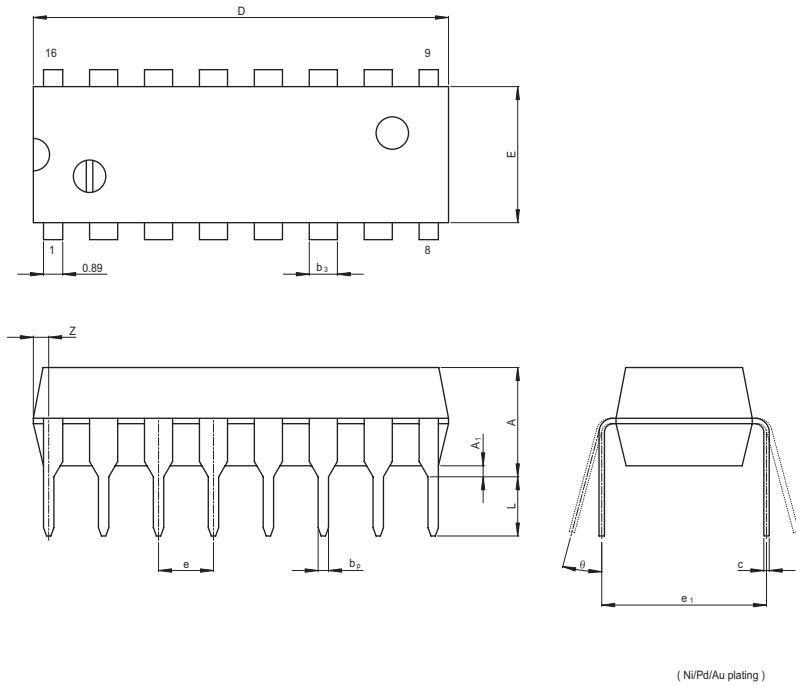






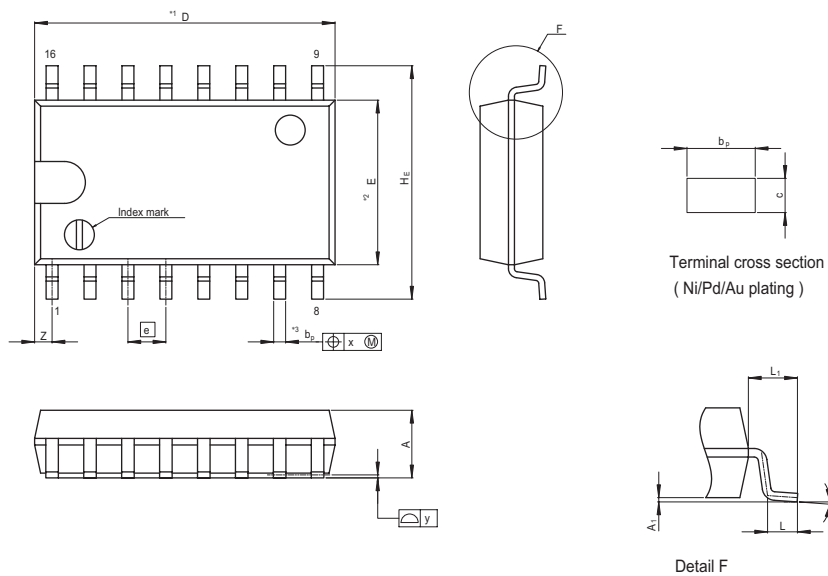
Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-DIP16-6.3x19.2-2.54	PRDP0016AE-B	DP-16FV	1.05g



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
e ₁	—	7.62	—
D	—	19.2	20.32
E	—	6.3	7.4
A	—	—	5.06
A ₁	0.51	—	—
b _p	0.40	0.48	0.56
b ₃	—	1.30	—
c	0.19	0.25	0.31
θ	0°	—	15°
e	2.29	2.54	2.79
Z	—	—	1.12
L	2.54	—	—

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-SOP16-5.5x10.06-1.27	PRSP0016DH-B	FP-16DAV	0.24g



NOTE)
 1. DIMENSIONS**1 (Nom)*AND**2 DO NOT INCLUDE MOLD FLASH.
 2. DIMENSION**3 DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	10.06	10.5
E	—	5.50	—
A ₂	—	—	—
A ₁	0.00	0.10	0.20
A	—	—	2.20
b _p	0.34	0.40	0.46
b ₁	—	—	—
c	0.15	0.20	0.25
c ₁	—	—	—
θ	0°	—	8°
HE	7.50	7.80	8.00
Ⓧ	—	1.27	—
x	—	—	0.12
y	—	—	0.15
Z	—	—	0.80
L	0.50	0.70	0.90
L ₁	—	1.15	—

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